

MH 249 CMOS High Sensitivity Omni-polar Hall Switch

a version

MH 249 α version Hall-effect sensor is a temperature stable, stress-resistant switch. Superior high-temperature performance is made possible through a dynamic offset cancellation that utilizes chopper-stabilization. This method reduces the offset voltage normally caused by device over molding, temperature dependencies, and thermal stress.

The MH 249 α version includes the following on a single silicon chip: voltage regulator, Hall voltage generator, small-signal amplifier, chopper stabilization, Schmitt trigger, and a short circuit protected open-drain output. Advanced CMOS wafer fabrication processing is used to take advantage of low-voltage requirements, component matching, very low input-offset errors, and small component geometries.

This device requires the presence of omni-polar magnetic fields for operation.

The MH 249 α version is rated for operation between the ambient temperatures -40° C and $+85^{\circ}$ C for the E temperature range. The package style available provide magnetically optimized solutions for most applications. Package SO is an SOT-23, a miniature low-profile surface-mount package.

The package type is in a lead (Pb)-free version was verified by third party Lab.

Features and Benefits

- CMOS Hall IC Technology
- Solid-State Reliability much better than reed switch
- Omni polar output switches with absolute value of North or South pole from magnet
- Operation down to 2.5V and up to 6 V.
- High Sensitivity for reed switch replacement
- Small Size in Sot 23 package

Applications

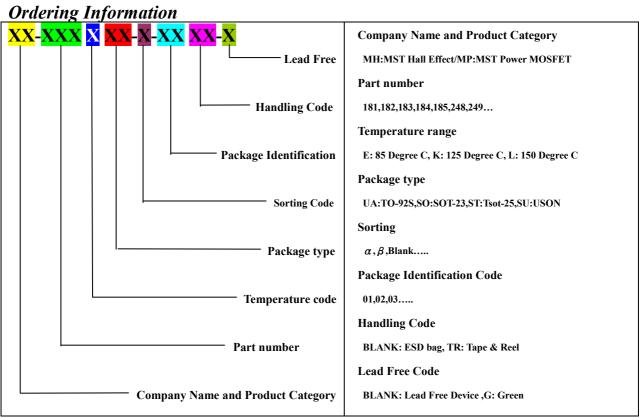
- Solid state switch
- Lid close sensor for power supply devices
- Magnet proximity sensor for reed switch replacement in high duty cycle applications.
- Safety Key
- Revolution counter



MH 249 CMOS High Sensitivity

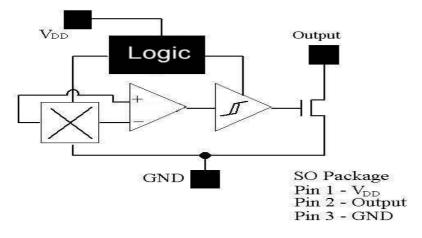
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Part No.	Temperature Suffix	Package Type	Package Identification
MH 249	E $(-40^{\circ}\text{C to} + 85^{\circ}\text{C})$	SO (SOT-23)	05

Functional Diagram



Note: Static sensitive device; please observe ESD precautions. Reverse V_{DD} protection is not included. For reverse voltage protection, a 100 Ω resistor in series with V_{DD} is recommended.

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MH249-a Absolute Maximum Ratings

Supply Voltage (Operating), V _{DD}	8V			
Supply Current (Fault), I _{DD}	3mA			
Output Voltage, V _{OUT}	8V			
Output Current (Fault), I _{OUT}	25mA			
Operating Temperature Range, T _A	-40°C to +85°C			
Storage Temperature Range, T _S	-55°C to +150°C			

MH249-a Electrical Specifications

DC operating parameters: $T_A = 25^{\circ}C$, $V_{DD}=3V_{DC}$ (unless otherwise specified).

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Supply Voltage	$ m V_{DD}$	Operating	2.5		6.0	V
Supply Current	I_{DD}	Average		1.5		mA
Output Current	I _{OUT}				10	mA
Saturation Voltage	V_{SAT}	$I_{OUT} = 1mA$			0.4	V

MH249-a Magnetic Specifications

DC operating parameters: $T_A = 25^{\circ}C$, $V_{DD}=3V_{DC}$ (unless otherwise specified).

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Operating	$\mathrm{B}_{\mathrm{OPS}}$	South pole to branded side, B > BOP, Vout On	0.6		6.0	mT
Point	$\mathrm{B}_{\mathrm{OPN}}$	North pole to branded side, B > BOP, Vout On	-6.0		-0.6	mT
Release	$\mathrm{B}_{\mathrm{RPS}}$	South pole to branded side, B < BRP, Vout Off	0.5		5.9	mT
Point	B_{RPN}	North pole to branded side, B < BRP, Vout Off	-5.9		-0.5	mT
Hysteresis	B _{HYS}	BOPx - BRPx		0.7		mT

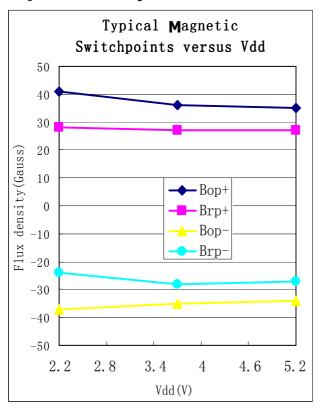
Note: 1 mT = 10 Gauss.

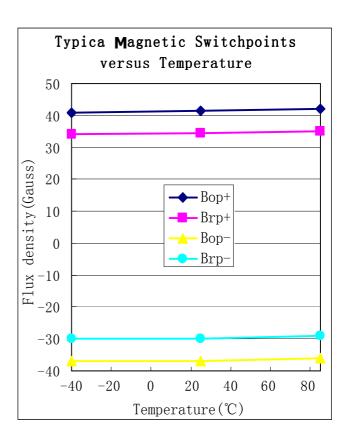


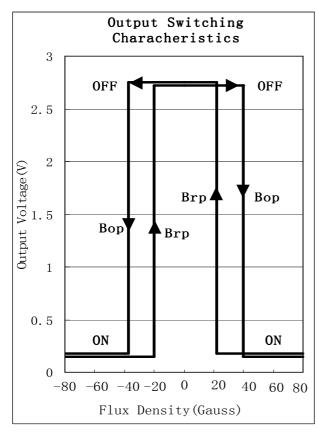
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Performance Graphs







Installation Comments

Consider temperature coefficients of Hall IC and magnetic, as well as air gap and life time variations. Observe temperature limits during wave soldering.



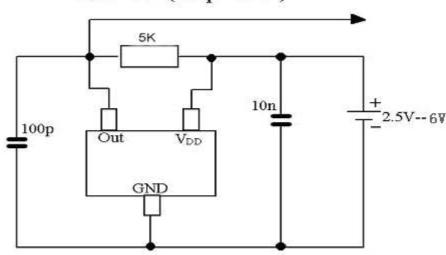
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Typical Application

SOT - 23 (Top View)



SOT-23 Package Physical Characteristics and sensor location

MH 249ESO 05 Package (Top View)

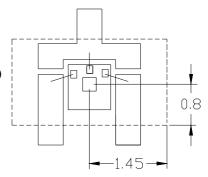
3.0 2.6 2.10 1.70 3.10 2.70

0.90 0.70 1.35 1.00 0.10 0.00

SOT-23 Hall Plate / Chip Location (Bottom view)

NOTES:

- 1. PINOUT (See Top View at left:)
 - Pin 1 VDD
 - Pin 2 Output
 - Pin 3 GND
- 2. Controlling dimension: mm;
- 3. Lead thickness after solder plating will be 0.254mm maximum.



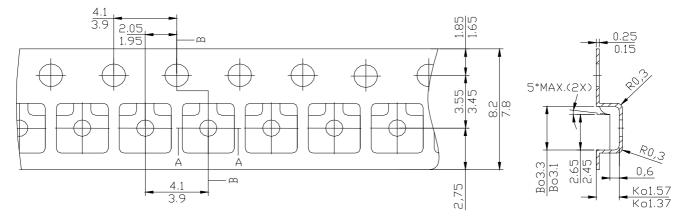


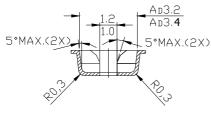
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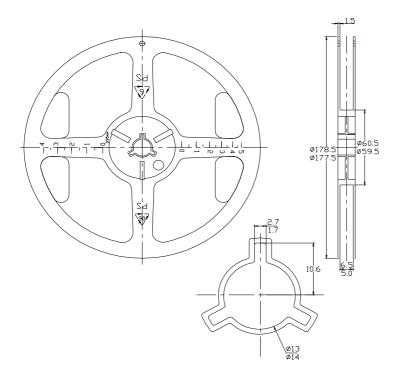
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Tape On Reel Dimension for Sot 23 package





SECTION A-A



NOTES:

- 1. Material: Conductive polystyrene;
- 2. DIM in mm;
- 10 sprocket hole pitch cumulative tolerance ±0.2;
- 4. Camber not to exceed 1mm in 100mm.
- Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole;
- 6. (S.R. OHM/SQ) Means surface